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D OR PW PACKAGE

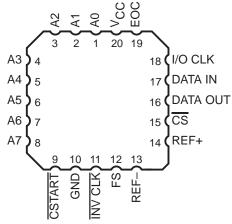
- Conversion Time ≤ 10 μs
- 10-Bit-Resolution ADC
- Programmable Power-Down Mode . . . 1 μA
- Wide Range Single-Supply Operation of 2.7 V dc to 5.5 V dc
- Analog Input Range of 0 V to V_{CC}
- Built-in Analog Multiplexer with 8 Analog Input Channels
- TMS320 DSP and Microprocessor SPI and QSPI Compatible Serial Interfaces
- End-of-Conversion (EOC) Flag
- Inherent Sample-and-Hold Function
- Built-In Self-Test Modes
- Programmable Power and Conversion Rate
- Asynchronous Start of Conversion for Extended Sampling
- Hardware I/O Clock Phase Adjust Input

description

The TLV1544 and TLV1548 are CMOS 10-bit switched-capacitor successive-approximation (SAR) analog-to-digital (A/D) converters. Each device has a chip select (CS), input-output clock (I/O CLK), data input (DATA IN) and serial data output (DATA OUT) that provide a direct 4-wire synchronous serial peripheral interface (SPI™, QSPI™) port of a host microprocessor. When interfacing with a TMS320 DSP, an additional frame sync signal (FS) indicates the start of a serial data frame. The devices allow high-speed data transfers from the host. The INV CLK input provides further timing flexibility for the serial interface.

In addition to a high-speed converter and versatile control capability, the device has an on-chip 11-channel multiplexer that can select any one of

(TOP VIEW) DATA OUT \square cs 16 2 15 DATA IN ☐ REF+ 14 I/O CLK 🖂 T REF-EOC I 13 FS \Box $V_{CC} \square$ 12 **INV CLK** A0 □ 6 11 oxdot GND 10 A1 🞞 □ CSTART 9 A2 🞞 **DB OR J PACKAGE** (TOP VIEW) A0 □ 10 □ V_{CC} 2 19 A1 🞞 A2 🗆 3 18 I/O CLK A3 🞞 4 17 DATA IN A4 🞞 5 16 III DATA OUT ☐ CS A5 6 15 7 14 A6 □ Α7 8 13 ☐ REF-CSTART 9 12 TTFS IIIV CLK GND □ 10 11 **FK PACKAGE** (TOP VIEW)



eight analog inputs or any one of three internal self-test voltages. The sample-and-hold function is automatic except for the extended sampling cycle, where the sampling cycle is started by the falling edge of asynchronous CSTART. At the end of the A/D conversion, the end-of-conversion (EOC) output goes high to indicate that the conversion is complete. The TLV1544 and TLV1548 are designed to operate with a wide range of supply voltages with very low power consumption. The power saving feature is further enhanced with a software-programmed power-down mode and conversion rate. The converter incorporated in the device features differential high-impedance reference inputs that facilitate ratiometric conversion, scaling, and isolation of analog circuitry from logic and supply noise. A switched-capacitor design allows low-error conversion over the full operating temperature range.

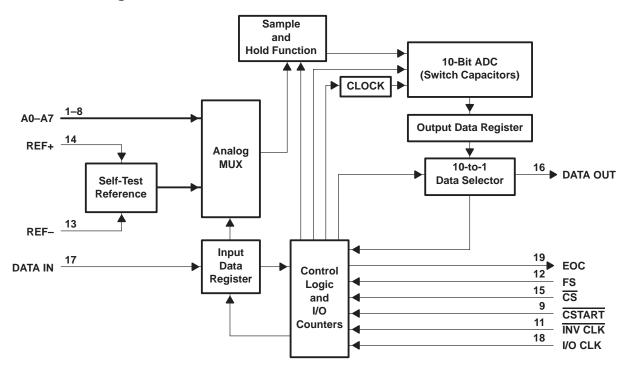
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description (continued)

The TLV1544 has four analog input channels while the TLV1548 has eight analog input channels. The TLV1544C and TLV1548C are characterized for operation from 0°C to 70°C. The TLV1544I and TLV1548I are characterized for operation over the full industrial temperature range of –40°C to 85°C. The TLV1548M is characterized for operation over the full military temperature range of –55°C to 125°C.

functional block diagram



Terminals shown are for the DB package.

AVAILABLE OPTIONS

			PACKAGE		
TA			SMALL OUTLINE		
	(DB)	(D)	(PW)	(J)	(FK)
0°C to 70°C	TLV1548CDB	TLV1544CD	TLV1544CPW		
-40°C to 85°C	TLV1548IDB	TLV1544ID	TLV1544IPW		
−55°C to 125°C				TLV1548MJ	TLV1548MFK

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR† ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	T _A = 125°C POWER RATING
DB	785 mW	8.7 mW/°C	393 mW	261 mW	_
D	799 mW	8.9 mW/°C	399 mW	266 mW	_
PW	604 mW	6.7 mW/°C	302 mW	201 mW	_
J	1894 mW	15.1 mW/°C	1212 mW	985 mW	379 mW
FK	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW

[†] This is the inverse of the traditional junction-to-ambient thermal resistance (ROJA). ROJA values are derived from Texas Instruments characterization data. Thermal resistance is not production tested and values are given for informational purposes only.



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Terminal Functions

TERMINAL			1/0	DESCRIPTION
NAME	NO.†	NO.‡	"	DECORN HON
A0-A3 A4-A7	6–9 –	1–4 5–8	I	Analog inputs. The analog inputs are internally multiplexed. (For a source impedance greater than 1 k Ω , the asynchronous start should be used to increase the sampling time.)
CS	16	15	I	Chip select. A high-to-low transition on $\overline{\text{CS}}$ resets the internal counters and controls and enables DATA IN, DATA OUT, and I/O CLK within the maximum setup time. A low-to-high transition disables DATA IN, DATA OUT, and I/O CLK within the setup time.
CSTART	10	9	I	Sampling/conversion start control. CSTART controls the start of the sampling of an analog input from a selected multiplex channel. A high-to-low transition starts the sampling of the analog input signal. A low-to-high transition puts the sample-and-hold function in hold mode and starts the conversion. CSTART is independent from I/O CLK and works when CS is high. The low CSTART duration controls the duration of the sampling cycle for the switched capacitor array. CSTART is tied to VCC if not used.
DATA IN	2	17	ı	Serial data input. The 4-bit serial data selects the desired analog input and test voltage to be converted next in a normal cycle. These bits can also set the conversion rate and enable the power-down mode. When operating in the microprocessor mode, the input data is presented MSB first and is shifted in on the first four rising ($\overline{\text{INV CLK}} = \text{V}_{\text{CC}}$) or falling ($\overline{\text{INV CLK}} = \text{GND}$) edges of I/O CLK (after $\overline{\text{CS}} \downarrow$). When operating in the DSP mode, the input data is presented MSB first and is shifted in on the first four falling ($\overline{\text{INV CLK}} = \text{V}_{\text{CC}}$) or rising ($\overline{\text{INV CLK}} = \text{GND}$) edges of I/O CLK (after FS \downarrow). After the four input data bits have been read into the input data register, DATA IN is ignored for the remainder of the current conversion period.
DATA OUT	1	16	0	Three-state serial output of the A/D conversion result. DATA OUT is in the high-impedance state when \overline{CS} is high and active when \overline{CS} is low or after FS \downarrow (in DSP mode). With a valid \overline{CS} signal, DATA OUT is removed from the high-impedance state and is driven to the logic level corresponding to the MSB or LSB value of the previous conversion result. DATA OUT changes on the falling (microprocessor mode) or rising (DSP mode) edge of I/O CLK.
EOC	4	19	0	End of conversion. EOC goes from a high to a low logic level on the tenth rising (microprocessor mode) or tenth falling (DSP mode) edge of I/O CLK and remains low until the conversion is complete and data is ready for transfer. EOC can also indicate that the converter is busy.
FS	13	12	I	DSP frame synchronization input. FS indicates the start of a serial data frame into or out of the device. FS is tied to V _{CC} when interfacing the device with a microprocessor.
GND	11	10		Ground return for internal circuitry. All voltage measurements are with respect to GND, unless otherwise noted.
INV CLK	12	11	I	Inverted clock input. INV CLK is tied to GND when an inverted I/O CLK is used as the source of the input clock. This affects both microprocessor and DSP interfaces. INV CLK is tied to V _{CC} if I/O CLK is not inverted. INV CLK can also invoke a built-in test mode.

[†]Terminal numbers are for the D package.



[‡] Terminal numbers are for the DB, J, and FK packages.

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Terminal Functions (Continued)

TEI	RMINAL		Ī	
NAME	NO.†	NO.‡	1/0	DESCRIPTION
I/O CLK	3	18	ı	Input/output clock. I/O CLK receives the serial I/O clock input in the two modes and performs the following four functions in each mode:
				Microprocessor mode
				When INVCLK = V _{CC} , I/O CLK clocks the four input data bits into the input data register on the first four rising edges of I/O CLK after CS↓ with the multiplexer address available after the fourth rising edge. When INV CLK = GND, input data bits are clocked in on the first four falling edges instead.
				On the fourth falling edge of I/O CLK, the analog input voltage on the selected multiplex input begins charging the capacitor array and continues to do so until the tenth rising edge of I/O CLK except in the extended sampling cycle where the duration of CSTART determines when to end the sampling cycle.
				Output data bits change on the first ten falling I/O clock edges regardless of the condition of INV CLK.
				I/O CLK transfers control of the conversion to the internal state machine on the tenth rising edge of I/O CLK regardless of the condition of INV CLK.
				Digital signal processor (DSP) mode
				When INV CLK = V _{CC} , I/O CLK clocks the four input data bits into the input data register on the first four falling edges of I/O CLK after FS↓ with the multiplexer address available after the fourth falling edges. When INV CLK = GND, input data bits are clocked in on the first four rising edges instead.
				On the fourth rising edge of I/O CLK, the analog input voltage on the selected multiplex input begins charging the capacitor array and continues to do so until the tenth falling edge of I/O CLK except in the extended sampling cycle where the duration of CSTART determines when to end the sampling cycle.
				Output data MSB shows after FS↓ and the rest of the output data bits change on the first ten rising I/O CLK edges regarless of the condition of INV CLK.
				 I/O CLK transfers control of the conversion to the internal state machine on the tenth falling edge of I/O CLK regardless of the condition of INV CLK.
REF+	15	14	ı	Upper reference voltage (nominally V_{CC}). The maximum input voltage range is determined by the difference between the voltages applied to REF+ and REF $-$.
REF-	14	13	Ī	Lower reference voltage (nominally ground)
VCC	5	20	I	Positive supply voltage

[†] Terminal numbers are for the D package.

detailed description

Initially, with $\overline{\text{CS}}$ high (inactive), DATA IN and I/O CLK are disabled and DATA OUT is in the high-impedance state. When the serial interface takes $\overline{\text{CS}}$ low (active), the conversion sequence begins with the enabling of I/O CLK and DATA IN and the removal of DATA OUT from the high-impedance state. The host then provides the 4-bit channel address to DATA IN and the I/O clock sequence to I/O CLK. During this transfer, the host serial interface also receives the previous conversion result from DATA OUT. I/O CLK receives an input sequence from the host that is from 10 to 16 clocks long. The first four valid I/O CLK cycles load the input data register with the 4-bit input data on DATA IN that selects the desired analog channel. The next six clock cycles provide the control timing for sampling the analog input. Sampling of the analog input is held after the first valid I/O CLK sequence of ten clocks. The tenth clock edge also takes EOC low and begins the conversion. The exact locations of the I/O clock edges depend on the mode of operation.

serial interface

The TLV1548 is compatible with generic microprocessor serial interfaces such as SPI and QSPI, and a TMS320 DSP serial interface. The internal latched flag If_mode is generated by sampling the state of FS at the falling edge of \overline{CS} . If_mode is set to one (for microprocessor) when FS is high at the falling edge of \overline{CS} , and If_mode is cleared to zero (for DSP) when FS is low at the falling edge of \overline{CS} . This flag controls the multiplexing of I/O CLK and the state machine reset function. FS is pulled high when interfacing with a microprocessor.



[‡] Terminal numbers are for the DB, J, and FK packages.

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I/O CLK

The I/O CLK can go up to 10 MHz for most of the voltage range when fast I/O is possible. The maximum I/O CLK is limited to 2.8 MHz for a supply voltage range from 2.7 V. Table 1 lists the maximum I/O CLK frequencies for all different supply voltage ranges. This also depends on input source impedance. For example, I/O CLK speed faster than 2.39 MHz is achievable if the input source impedance is less than 1 k Ω .

MAXIMUM INPUT SOURCE IMPEDANCE I/O CLK VCC RESISTANCE (Max) $1 \text{ k}\Omega$ 2.39 MHz 2.7 V 5 K 100Ω 2.81 MHz $1 \text{ k}\Omega$ 7.18 MHz 4.5 V 1 K 100 Ω 10 MHz

Table 1. Maximum I/O CLK Frequency

microprocessor serial interface

Input data bits from DATA IN are clocked in on the first four rising edges of the I/O CLK sequence if INV CLK is held high when the device is in microprocessor interface mode. Input data bits are clocked in on the first four falling edges of the I/O CLK sequence if INV CLK is held low. The MSB of the previous conversion appears on DATA OUT on the falling edge of CS. The remaining nine bits are shifted out on the next nine edges (depending on the state of INV CLK) of I/O CLK. Ten bits of data are transmitted to the host through DATA OUT.

A minimum of 9.5 clock pulses is required for the conversion to begin. On the tenth clock rising edge, the EOC output goes low and returns to the high logic level when the conversion is complete; then the result can be read by the host. On the tenth clock falling edge, the internal logic takes DATA OUT low to ensure that the remaining bit values are zero if the I/O CLK transfer is more than ten clocks long.

CS is inactive (high) between serial I/O CLK transfers. Each transfer takes at least ten I/O CLK cycles. The falling edge of CS begins the sequence by removing DATA OUT from the high-impedance state. The rising edge of CS ends the sequence by returning DATA OUT to the high-impedance state within the specified delay time. Also, the rising edge of CS disables I/O CLK and DATA IN within a setup time. A conversion does not begin until the tenth I/O CLK rising edge.

A high-to-low transition on \overline{CS} within the specified time during an ongoing cycle aborts the cycle, and the device returns to the initial state (the output data register holds the previous conversion result). \overline{CS} should not be taken low close to completion of conversion because the output data can be corrupted.



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DSP interface

The TLV1544/1548 can also interface with a DSP, from the TMS320 family for example, through a serial port. The analog-to-digital converter (ADC) serves as a slave device where the DSP supplies FS and the serial I/O CLK. Transmit and receive operations are concurrent. The falling edge of FS must occur no later than seven I/O CLK periods after the falling edge of $\overline{\text{CS}}$.

DSP I/O cycles differ from microprocessor I/O cycles in the following ways:

- When interfaced with a DSP, the output data MSB is available after FS↓. The remaining output data changes on the rising edge of I/O CLK. The input data is sampled on the first four falling edges of I/O CLK after FS↓ and when INV CLK is high, or the first four rising edges of I/O CLK after FS↓ and when INV CLK is low. This operation is inverted when interfaced with a microprocessor.
- A new DSP I/O cycle is started on the rising edge of I/O CLK after the rising edge of FS. The internal state
 machine is reset on each falling edge of I/O CLK when FS is high. This operation is opposite when interfaced
 with a microprocessor.
- The TLV1544/1548 supports a 16-clock cycle when interfaced with a DSP. The output data is padded with six trailing zeros when it is operated in DSP mode.

Table 2. TLV1544/TLV1548 Serial Interface Modes

1/0	INTERFACE MODE				
1/0	MICROPROCESSOR ACTION	DSP ACTION			
CS↓	Initializes counter	Samples state of FS			
CS↑	Resets state machine and disable I/O	Disables I/O			
FS	Connects to V _{CC}	Connects to DSP FSX output Initializes the state machine at each CLK↓ after FS↑ Starts a new cycle at each CLK↑ following the initialization (initializes the counter)			
I/O CLK	Starts sampling of the analog input started at fourth I/O CLK↑ Conversion started at tenth I/O CLK↑	Starts sampling of the analog input at fourth I/O CLK↓ Starts sampling of the analog input at tenth I/O CLK↓			
DATA IN	Samples input data on I/O CLK↑ (INV CLK high) Samples input data on I/O CLK↓ (INV CLK low)	Samples input data at I/O CLK↓ (INV CLK high) Samples input data at I/O CLK↑ (INV CLK low)			
DATA OUT	Makes MSB available on CS ↓ Changes remaining data on I/O CLK↓	Makes MSB available FS↓ Changes remaining data at each following I/O CLK↑ after FS↓			



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input data bits

DATA IN is internally connected to a 4-bit serial input data register. The input data selects a different mode or selects different analog input channels. The host provides the data word with the MSB first. Each data bit clocks in on the edge (rising or falling depending on the status of INV CLK and FS) of the I/O CLK sequence. The input clock can be inverted by grounding INV CLK (see Table 3 for the list of software programmed operations set by the input data).

Table 3. TLV1544/1548 Software-Programmed Operation Modes

	INPUT DAT	A BYTE	
FUNCTION SELECT	A3 – A	A0	COMMENT
	BINARY	HEX	
Analog channel A0 for TLV1548 selected	0000b	0h	Channel 0 for TLV1544
Analog channel A1 for TLV1548 selected	0001b	1h	
Analog channel A2 for TLV1548 selected	0010b	2h	Channel 1 for TLV1544
Analog channel A3 for TLV1548 selected	0011b	3h	
Analog channel A4 for TLV1548 selected	0100b	4h	Channel 2 for TLV1544
Analog channel A5 for TLV1548 selected	0101b	5h	
Analog channel A6 for TLV1548 selected	0110b	6h	Channel 3 for TLV1544
Analog channel A7 for TLV1548 selected	0111b	7h	
Software power down set	1000b	8h	No conversion result (cleared by any access)
Fast conversion rate (10 μs) set	1001b	9h	No conversion result (cleared by setting to fast)
Slow conversion rate (40 µs) set	1010b	Ah	No conversion result (cleared by setting to slow)
Self-test voltage (V _{ref+} - V _{ref-})/2 selected	1011b	Bh	Output result = 200h
Self-test voltage V _{ref} – selected	1100b	Ch	Output result = 000h
Self-test voltage V _{ref +} selected	1101b	Dh	Output result = 3FFh
Reserved	1110b	Eh	No conversion result
Reserved	1111b	Fh	No conversion result

analog inputs and internal test voltages

The eight analog inputs and the three internal test inputs are selected by the 11-channel multiplexer according to the input data bit as shown in Table 3. The input multiplexer is a break-before-make type to reduce input-to-input noise injection resulting from channel switching.

The device can be operated in two distinct sampling modes: normal sampling mode (fixed sampling time) and extended sampling mode (flexible sampling time). When $\overline{\text{CSTART}}$ is held high, the device is operated in normal sampling mode. When operated in normal sampling mode, sampling of the analog input starts on the rising edge of the fourth I/O CLK pulse in the microprocessor interface mode (and on the fourth falling edge of I/O CLK in the DSP interface mode). Sampling continues for 6 I/O CLK periods. The sample is held on the falling edge of the tenth I/O CLK pulse in the microprocessor interface mode. The sample is held on the falling edge of the tenth I/O CLK pulse in the DSP interface mode. The three test inputs are applied to the multiplexer, then sampled and converted in the same manner as the external analog inputs.



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converter

The CMOS threshold detector in the successive-approximation conversion system determines the value of each bit by examining the charge on a series of binary-weighted capacitors (see Figure 1). In the first phase of the conversion process, the analog input is sampled by closing the S_C switch and all S_T switches simultaneously. This action charges all of the capacitors to the input voltage.

In the next phase of the conversion process, all S_T and S_C switches are opened and the threshold detector begins identifying bits by identifying the charge (voltage) on each capacitor relative to the reference (REF –) voltage. In the switching sequence, ten capacitors are examined separately until all ten bits are identified and then the charge-convert sequence is repeated. In the first step of the conversion phase, the threshold detector looks at the first capacitor (weight = 512). Node 512 of this capacitor is switched to the REF+ voltage, and the equivalent nodes of all the other capacitors on the ladder are switched to REF –. If the voltage at the summing node is greater than the trip point of the threshold detector (approximately one-half V_{CC}), a bit 0 is placed in the output register and the 512-weight capacitor is switched to REF –. If the voltage at the summing node is less than the trip point of the threshold detector, a bit 1 is placed in the register and the 512-weight capacitor remains connected to REF + through the remainder of the successive-approximation process. The process is repeated for the 256-weight capacitor, the 128-weight capacitor, and so forth down the line until all bits are counted.

With each step of the successive-approximation process, the initial charge is redistributed among the capacitors. The conversion process relies on charge redistribution to count and weigh the bits from MSB to LSB.

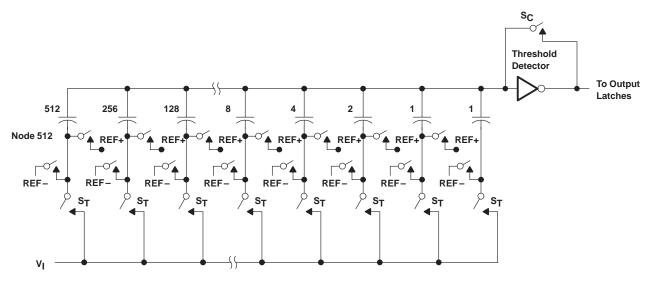


Figure 1. Simplified Model of the Successive-Approximation System



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extended sampling, asynchronous start of sampling: CSTART operation

The extended sampling mode of operation programs the acquisition time (t_{ACQ}) of the sample-and-hold circuit. This allows the analog inputs of the device to be directly interfaced to a wide range of input source impedances. The extended sampling mode consumes higher power depending on the duration of the sampling period chosen.

CSTART controls the sampling period and starts the conversion. The falling edge of CSTART initiates the sampling period of a preset channel. The low time of CSTART controls the acquisition time of the input sample-and-hold circuit. The sample is held on the rising edge of CSTART. Asserting CSTART causes the converter to perform a new sample of the signal on the preset valid MUX channel (one of the eight) and discard the current conversion result ready for output. Sampling continues as long as CSTART is active (negative). The rising edge of CSTART ends the sampling cycle. The conversion cycle starts two internal system clocks after the rising edge of CSTART.

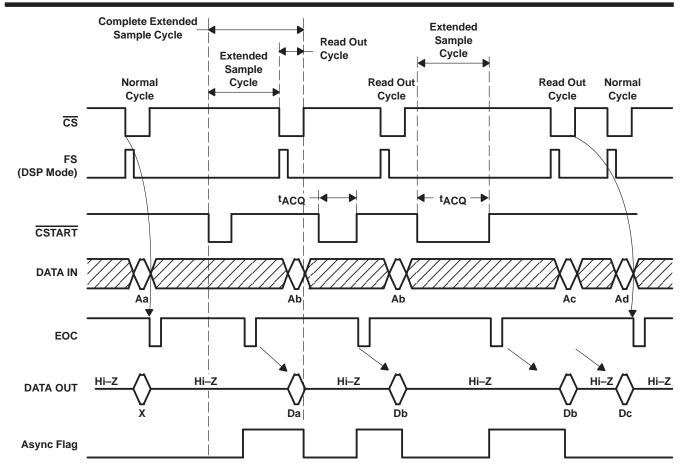
Once the conversion is complete, the processor can initiate a normal I/O cycle to read the conversion result and set the MUX address for the next conversion. Since the internal flag AsyncFlag is set high, this flag setting indicates the cycle is an output cycle, so no conversion is performed during the cycle. The internal state machine tests the AsyncFlag on the falling edge of $\overline{\text{CS}}$. AsyncFlag is set high at the rising edge of $\overline{\text{CS}}$ and it is reset low at the rising edge of each $\overline{\text{CS}}$. A conversion cycle follows a sampling cycle only if AsyncFlag is tested as low at the falling edge of $\overline{\text{CS}}$. As shown in Figure 2, an asynchronous I/O cycle can be removed by two consecutive normal I/O cycles.

Table 4. TLV1544/1548 Hardware Configuration for Different Operating Modes

OPERATING MODES	CS	CSTART	AsyncFlag at CS ↓	S↓ ACTION	
Normal sampling	Low	High	Low	Fixed 6 I/O CLK sampling, synchronous conversion follows	
Normal I/O (read out only)	Low	High	High	No sampling, no conversion	
Extended sampling	High	Low	N/A	Flexible sampling period controlled by CSTART, asynchronous conversion follows	



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NOTES: A. Aa = Address for input channel a.

B. Da = Conversion result from channel a.

Figure 2. Extended Sampling Operation

reference voltage inputs

There are two reference inputs used with the TLV1544/TLV1548, REF+ and REF-. These voltage values establish the upper and lower limits of the analog inputs to produce a full-scale and zero-scale reading respectively. The values of REF+, REF-, and the analog input should not exceed the positive supply or be lower than GND consistent with the specified absolute maximum ratings. The digital output is at full scale when the input signal is equal to or lower than REF+ and is at zero when the input signal is equal to or lower than REF-.

programmable conversion rate

The TLV1544/TLV1548 offers two conversion rates to maximize battery life when high-speed operation is not necessary. The conversion rate is programmable. Once the conversion rate has been selected, it takes effect immediately in the same cycle and stays at the same rate until the other rate is chosen. The conversion rate should be set at power up. Activation and deactivation of the power-down state (digital logic active) has no effect on the preset conversion rate.



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	CONVERSION TIME.	AVAILABLE VCC	TYPICAL SUPPLY CURR		SUPPLY CURRE	ENT, I _{CC}	
CONVERSION RATE	t _{conv}	RANGE	INPUT DATA	OPERATING		POWER DOWN	
Fast conversion speed	7 μs typ	5.5 V to 3.3 V	9h	0.6 mA typ 1.5 mA max		1 μA typ	
Slow conversion speed	15 μs typ	5.5 V to 2.7 V	Ah	0.4 mA typ		1 μA typ	

programmable power-down state

The device is put into the power-down state by writing 8h to DATA IN. The power-up state is restored during the next active access by pulling \overline{CS} low. The conversion rate selected before the device is put into the power-down state is not affected by the power-down mode. Power-down can be used to achieve even lower power consumption. This is because the sustaining power (when not converting) is only 1.3 mA maximum and standby power is only 1 μ A maximum. (By averaging out the power consumption can be much lower than the 1 mA peak when the conversion throughput is lower.)

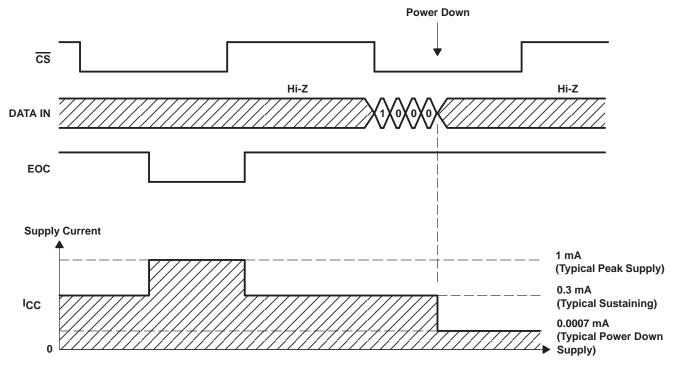


Figure 3. Typical Supply Current During Conversion/Power Down

power up and initialization

After power up, if operating in DSP mode, \overline{CS} and FS must be taken from high to low to begin an I/O cycle. EOC is initially high, and the input data register is set to all zeroes. The content of the output data register is random, and the first conversion result should be ignored. For initialization during operation, \overline{CS} is taken high and returned low to begin the next I/O cycle. The first conversion after the device has returned from the power-down state can be invalid and should be disregarded.

When power is first applied to the device, the conversion rate must be programmed, and the internal Async Flag must be taken low once. The rising edge of \overline{CS} of the same cycle then takes Async Flag low.



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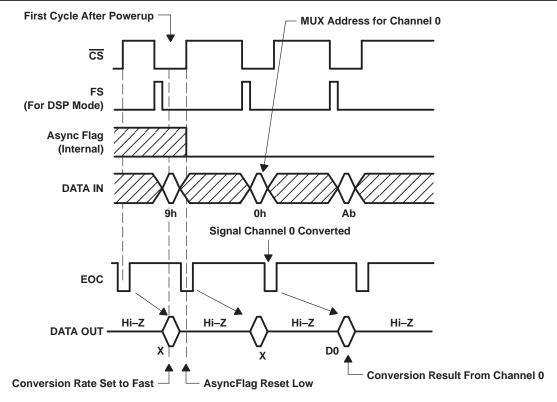


Figure 4. Power Up Initialization

input clock inversion - INV CLK

The input data register uses I/O CLK as the source of the sampling clock. This clock can be inverted to provide more setup time. INV CLK can invert the clock. When INV CLK is grounded, the input clock for the input data register is inverted. This allows an additional one-half I/O CLK period for the input data setup time. This is useful for some serial interfaces. When the input sampling clock is inverted, the output data changes at the same time that the input data is sampled.

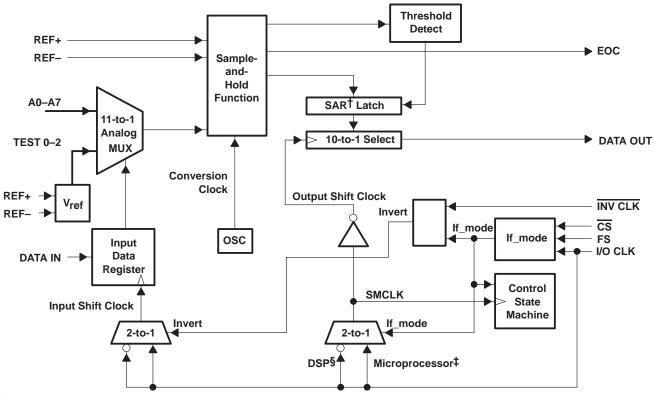
Table 6. Function of INV CLK

C	CLOCK	I/O CLK ACTIVE EDGE			
INV CLK	FS at CS↓	OUTPUT DATA CHANGES ON	INPUT DATA SAMPLED ON		
High	High (MP [†] mode)	\	↑		
High	Low (DSP [‡] mode)	1	\downarrow		
Low	High (MP [†] mode)	\downarrow	\downarrow		
Low	Low (DSP [‡] mode)	1	1		

TMP = microprocessor mode



[‡]DSP = digital signal processor mode



[†] Successive approximation register

Figure 5. Clock Scheme

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC} (see Note 1)		
Input voltage range, V _I (any input)		$-0.3 \text{ V to V}_{CC} + 0.3 \text{ V}$
Output voltage range, VO		$-0.3 \text{ V to V}_{CC} + 0.3 \text{ V}$
Positive reference voltage, V _{ref+}		V _{CC} + 0.1 V
Negative reference voltage, V _{ref}		0.1 V
Peak input current, I _I (any input)		±20 mA
Peak total input current (all inputs)		30 mA
Operating free-air temperature range, T _A :	TLV1544C, TLV1548C .	0°C to 70°C
	TLV1544I, TLV1548I	–40°C to 85°C
	TLV1548M	
Storage temperature range, T _{stq}		
Lead temperature 1,6 mm (1/16 inch) from		

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to GND with REF - and GND wired together (unless otherwise noted).



[‡] If_mode = 1, microprocessor interface mode

[§] If mode = 0, DSP interface mode

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recommended operating conditions

		MIN	NOM	MAX	UNIT	
Supply voltage, V _{CC}		2.7		5.5	V	
Positive reference voltage, V _{ref+} (see Note 2)			VCC		V	
Negative reference voltage, V _{ref} (see Note 2)			0		V	
Differential reference voltage, V _{ref+} – V _{ref-} (se	ee Note 2)	2.5	VCC	V _{CC} +0.2	V	
Analog input voltage, V _{I (analog)} (see Note 2)		0		VCC	V	
High-level control input voltage, VIH		2.1			V	
Low-level control input voltage, V _{IL}				0.6	V	
Setup time, input data bits valid before I/O CLK	(↑↓, t _{Su(A)} (see Figure 9)	100			ns	
Hold time, input data bits valid after I/O CLK↑↓	, t _{h(A)} (see Figure 9)	5	30		ns	
Setup time, CS↓ to I/O CLK↑, t _{SU(CS)}	See Figure 10	5	30		ns	
Hold time, I/O CLK↓ to CS↑, th(CS)	See Figure 10	65			ns	
Pulse duration, FS high, t _{wH(FS)}	See Figure 12	1			I/O CLK periods	
Pulse duration, CSTART, tw(CSTART)	Source impedance \leq 1 k Ω , V _{CC} = 5.5 V, See Figure 14	0.84			μs	
Setup time, CS↑ to CSTART↓, t _{SU} (CSTART)	See Figure 14	10			ns	
Clock from the property of 1/O Cl V. for the	V _{CC} = 5.5 V	0.1	6	10		
Clock frequency at I/O CLK, f _{CLK}	V _{CC} = 2.7 V	0.1	2	2.81	MHz	
Bules duration I/O CLK high t	V _{CC} = 5.5 V	50			ns	
Pulse duration, I/O CLK high, t _{wH(I/O)}	V _{CC} = 2.7 V	100				
Pulse duration, I/O CLK low, t _{wL(I/O)}	V _{CC} = 5.5 V	50			ns	
Pulse duration, I/O CER low, t _{WE} (I/O)	V _{CC} = 2.7 V	100			115	
Transition time, I/O CLK, t _{t(I/O)} (see Figure 11	and Note 4)			1	μs	
Transition time, DATA IN, t _{t(DATA IN)} (see Figu	ıre 9)			10	μs	
Transition time, CS, t _{t(CS)} (see Figure 10)				10	μs	
Transition time, FS, t _{t(FS)} (see Figure 13)				10	μs	
Transition time, CSTART, tt(CSTART) (see Figu	ure 14)			10	μs	
	TLV1544C, TLV1548C	0		70		
Operating free-air temperature, TA	TLV1544I, TLV1548I	-40		85	°C	
	TLV1548M	-55		125		
	TLV1544C, TLV1548C			115		
Junction temperature, T _J	TLV1544I, TLV1548I			115	°C	
	TLV1548M			150		

NOTES: 2. Analog input voltages greater than the voltage applied to REF+ convert as all ones (111111111111), while input voltages less than the voltage applied to REF- convert as all zeros (000000000000). The device is functional with reference (V_{ref+} – V_{ref-}) down to 1 V; however, the electrical specifications are no longer applicable.

3. To minimize errors caused by noise at \overline{CS} , the internal circuitry waits for a setup time after \overline{CS} ↓ before responding to control input signals. No attempt should be made to clock in an input dat until the minimum \overline{CS} setup time has elapsed.

4. This is the time required for the I/O CLK signal to fall from V_{IH}max to V_{IL}min or to rise from V_{IL}max to V_{IH}min. In the vicinity of normal room temperature, the devices function with an input clock transition time as slow as 1 μs for remote data-acquisition applications where the sensor and the A/D converter are placed several feet away from the controlling microprocessor.



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electrical characteristics over recommended operating free-air temperature range, $V_{CC} = V_{ref+} = 2.7 \text{ V}$ to 5.5 V, I/O CLK frequency = 2.2 MHz (unless otherwise noted)

	PARAMETER	TEST CONI	MIN	TYP [†]	MAX	UNIT	
V	Lligh lovel output valtage	V _{CC} = 5.5 V,	I _{OH} = -0.2 mA	2.4			V
VOH	High-level output voltage	V _{CC} = 2.7 V,	I _{OH} = -20 μA	VCC-0.1			V
V	Law law law at water at walks are	V _{CC} = 5.5 V,	I _{OL} = 0.8 mA			0.4	V
VOL	Low-level output voltage	V _{CC} = 2.7 V,	I _{OL} = 20 μA			0.1	V
1	High important autout autout	$V_O = V_{CC}$	CS = V _{CC}		1	2.5	A
loz	High-impedance output current	$V_{O} = 0,$	CS = V _{CC}		-1	-2.5	μΑ
lн	High-level input current	VI = VCC			0.005	2.5	μΑ
I _I L	Low-level input current	V _I = 0			-0.005	2.5	μΑ
		Conversion speed = fast, For all digital inputs, $0 \le V_1 \le 0.3 \text{ V or}$ $V_1 \ge V_{CC} - 0.3 \text{ V}$	V _{CC} = 3.3 V to 5.5 V		0.6	1.5	
ICC	Operating supply current	Conversion speed = slow, For all digital inputs,	V _{CC} = 3.3 V to 5.5 V		0.4	1	mA
		$0 \le V_I \le 0.3 \text{ V or}$ $V_I \ge V_{CC} - 0.3 \text{ V}$	V _{CC} = 2.7 V to 3.3 V	0.35		0.75	
1	Extended sampling mode	V _{CC} = 3.3 V to 5.5 V			1.5		mA
ICC(ES)	operating current	V _{CC} = 2.7 V to 3.3 V			1		mA
ICC(ST)	Sustaining supply current	Conversion speed = slow, For all digital inputs, $0 \le V_1 \le 0.3 \text{ V or}$ $V_1 \ge V_{CC} - 0.3 \text{ V}$	V _{CC} = 2.7 V to 3.3 V		0.3		mA
I _{CC(PD)}	Power-down supply current	For all digital inputs, $0 \le V_I \le 0.3 \text{ V or } V_I \ge V_{CC} - V_{CC} = 0.3 \text{ V}$					μΑ
1	Calcated abannal lackage august	Selected channel at V _{CC} , u	Selected channel at V _{CC} , unselected channel at 0 V			1	μА
likg	Selected channel leakage current	Selected channel at 0 V, unselected channel at V _{CC}				-1	μΑ
	Maximum static analog reference current into REF+	V _{ref+} = V _{CC} = 5.5 V,	V _{ref} = GND			1	μΑ
C. +	Input capacitance, analog inputs				20	55	nE.
C _i ‡	Input capacitance, control inputs				20	15	pF
7. +	Input multiplexer on resistance	V _{CC} = 4.5 V				1	kΩ
Z _i ‡	input multiplexer on resistance	V _{CC} = 2.7 V				5	K32

 $[\]dagger$ All typical values are at V_{CC} = 5 V, T_A = 25°C.

[‡] Not production tested.

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operating characteristics over recommended operating free-air temperature range, $V_{CC} = V_{ref+} = 2.7 \text{ V}$ to 5.5 V, I/O CLK frequency = 2.2 MHz (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	түр†	MAX	UNIT
Linearity error (see Note 6)			±0.5	±1	LSB	
Differential linearity error		See Note 2		±0.5	±1	LSB
Offset error (see Note 7)		See Note 2			±1.5	LSB
Gain error (see Note 7)		See Note 2			±1	LSB
Total unadjusted error (see Note	8)				±1.75	LSB
		DATA IN = 1011		512		
Self-test output code (see Table 3	DATA IN - 1100		0			
	DATA IN = 1101		1023			
Conversion time	Fast conversion speed	See Figures 15		7	10	μs
Conversion time	Slow conversion speed	through 17		15	25	μs
Total cycle time (access,	Fast conversion speed	See Figures 15 through 18 and Notes 10, 11, 12			10.1 + 10 I/O CLK	
to CS delay)	Slow conversion speed	See Figures 15 through 18 and Notes 10 and 12			40.1 + 10 I/O CLK	μs
Channel acquisition time (sample	2)	See Figures 15 through 18 and Note 10			6	I/O CLK periods
Valid time, DATA OUT remains va	alid after I/O CLK↓	See Figure 11	50			ns
Delay time, I/O CLK high to FS hi	igh	See Figure 13	5	30	50	ns
Delay time, I/O CLK high to FS lo)W	See Figure 13	10	30	60	ns
Delay time, EOC↑ to CS low		See Figure 14 and Note 5	100			ns
Delay time, CS↓ to FS↑	See Figures 17 and 18	1		7	I/O CLK periods	
Delay time, 10th I/O CLK low to 0 conversion (see Note 13)	CS low to abort	See Figure 10			1.1	μs
	Linearity error (see Note 6) Differential linearity error Offset error (see Note 7) Gain error (see Note 7) Total unadjusted error (see Note Self-test output code (see Table 3) Conversion time Total cycle time (access, sample, conversion and EOC↑ to CS↓ delay) Channel acquisition time (sample Valid time, DATA OUT remains value) Delay time, I/O CLK high to FS hole of the CS↓ to CS low Delay time, EOC↑ to CS low Delay time, CS↓ to FS↑ Delay time, 10th I/O CLK low to CS↓	Linearity error (see Note 6) Differential linearity error Offset error (see Note 7) Gain error (see Note 7) Total unadjusted error (see Note 8) Self-test output code (see Table 3 and Note 9) Conversion time Fast conversion speed Slow conversion speed Slow conversion speed Fast conversion speed Slow conversion speed Fast conversion speed	Linearity error (see Note 6) Differential linearity error Offset error (see Note 7) Gain error (see Note 7) Total unadjusted error (see Note 8) Self-test output code (see Table 3 and Note 9) DATA IN = 1011 DATA IN = 1101 See Figures 15 through 17 See Figures 15 through 17 See Figures 15 through 18 and Notes 10, 11, 12 See Figures 15 through 18 and Notes 10 and 12 Channel acquisition time (sample) Valid time, DATA OUT remains valid after I/O CLK↓ Delay time, I/O CLK high to FS high Delay time, I/O CLK high to FS low Delay time, EOC↑ to CS low Delay time, CS↓ to FS↑ Delay time, CS↓ to FS↑ Delay time, I/O CLK low to CS low to abort See Figure 10 See Figure 10 See Figure 10 See Figure 10 See Figure 11 See Figure 11	Linearity error (see Note 6) Differential linearity error Gain error (see Note 7) Total unadjusted error (see Note 8) Self-test output code (see Table 3 and Note 9) Part In	PARAMETER CONDITIONS MIN TYPI Linearity error (see Note 6) ±0.5 ±0.5 Differential linearity error See Note 2 ±0.5 Offset error (see Note 7) See Note 2 ±0.5 Gain error (see Note 7) See Note 2 ±0.5 Total unadjusted error (see Note 8) DATA IN = 1011 512 DATA IN = 1101 1023 50 Conversion time Fast conversion speed See Figures 15 7 Total cycle time (access, sample, conversion and EOC↑ to CS ↓ delay) Fast conversion speed See Figures 15 15 See Figures 15 through 18 and Notes 10, 11, 12 See Figures 15 15 Channel acquisition time (sample) See Figures 15 15 Valid time, DATA OUT remains valid after I/O CLK↓ See Figure 15 5 Delay time, I/O CLK high to FS low See Figure 13 5 30 Delay time, I/O CLK high to FS low See Figure 13 10 30 Delay time, CS↓ to FS↑ See Figure 17 100 100	Linearity error (see Note 6) ±0.5 ±1

[†] All typical values are at $T_A = 25$ °C.

NOTES: 2. Analog input voltages greater than that applied to REF+ convert as all ones (111111111111), while input voltages less than that applied to REF- convert as all zeros (000000000000). The device is functional with reference down to 1 V (V_{ref}+-V_{ref}-1); however, the electrical specifications are no longer applicable.

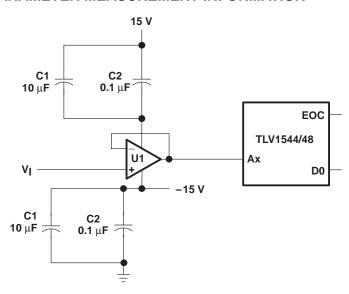
- 5. For all operating modes.
- 6. Linearity error is the maximum deviation from the best straight line through the A/D transfer characteristics.
- 7. Zero error is the difference between 0000000000 and the converted output for zero input voltage. Full-scale error is the difference between 1111111111 and the converted output for full-scale input voltage.
- 8. Total unadjusted error comprises linearity, zero-scale, and full-scale errors.
- 9. Both the input data and the output codes are expressed in positive logic.
- 10. I/O CLK period = 1/(I/O CLK frequency) (see Figure 8).
- 11. For 3.3 V to 5.5 V only
- 12. For microprocessor mode
- 13. Any transitions of \overline{CS} are recognized as valid only when the level is maintained for a setup time after the transition.



operating characteristics over recommended operating free-air temperature range, $V_{CC} = V_{ref+} = 2.7 \text{ V}$ to 5.5 V, I/O CLK frequency = 2.2 MHz (unless otherwise noted) (continued)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
td(I/O-DATA)	Delay time, I/O CLK low to DATA OUT valid	See Figure 11			50	ns
td(I/O-EOC)	Delay time, 10th I/O CLK↓ to EOC low	See Figure 12		70	240	ns
tPZH, tPZL	Enable time, CS low to DATA OUT valid (MSB driven)	See Figure 8		0.7	1.3	μs
tPHZ, tPLZ	Disable time, CS high to DATA OUT invalid (high impedance)	See Figure 8		70	150	ns
tf(EOC)	Fall time, EOC	See Figure 12		15	50	ns
tr(bus)	Rise time, output data bus at 2.2 MHz I/O CLK	See Figure 11		50	250	ns
tf(bus)	Fall time, output data bus at 2.2 MHz I/O CLK	See Figure 11		50	250	ns

[†] All typical values are at $T_A = 25$ °C.



LOCATION	DESCRIPTION	PART NUMBER
U1	OP27	_
C1	10-μF 35-V tantalum capacitor	_
C2	0.1-μF ceramic NPO SMD capacitor	AVX 12105C104KA105 or equivalent

Figure 6. Analog Input Buffer to Analog Inputs

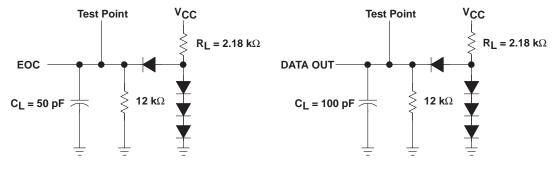
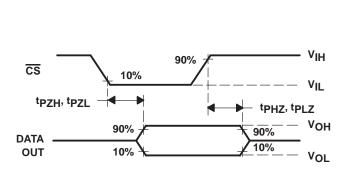


Figure 7. Load Circuits





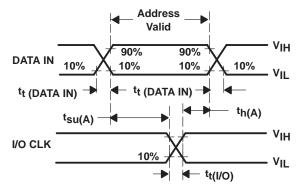


Figure 8. DATA OUT to Hi-Z Voltage Waveforms

Figure 9. DATA IN Setup Voltage Waveforms

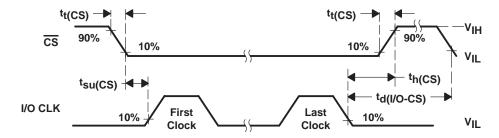


Figure 10. CS and I/O CLK Voltage Waveforms

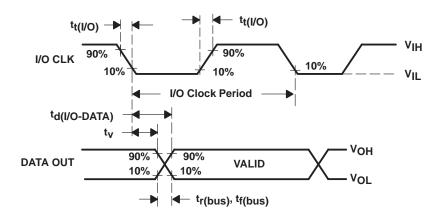


Figure 11. DATA OUT and I/O CLK Voltage Waveforms

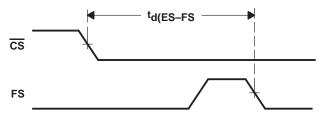


Figure 12. CS Low to FS Low



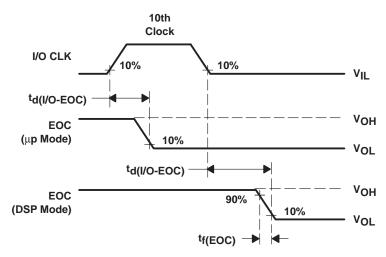


Figure 13. I/O CLK and EOC Voltage Waveforms

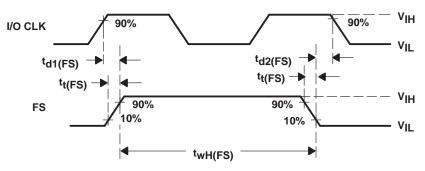


Figure 14. FS and I/O CLK Voltage Waveforms

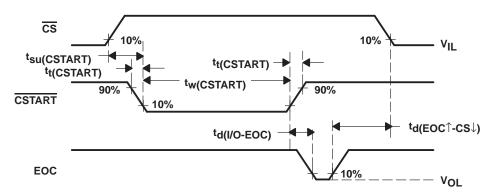
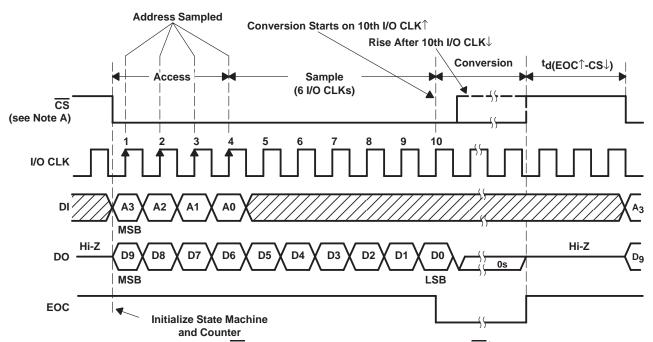
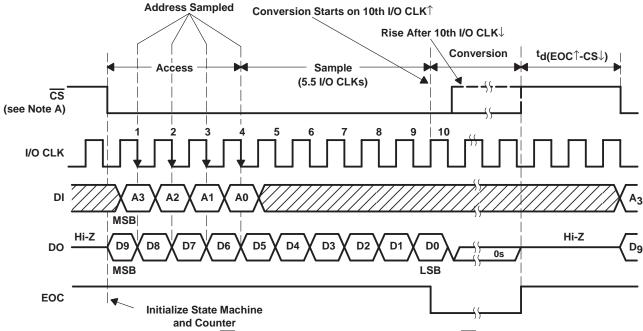


Figure 15. CSTART and CS Waveforms



NOTE A: To minimize errors caused by noise at \overline{CS} , the internal circuitry waits for a setup time after \overline{CS} ↓ before responding to control input signals. No attempt should be made to clock in input data until the minimum \overline{CS} setup time elapses.

Figure 16. Microprocessor Interface Timing (Normal Sample Mode, INV CLK = High)



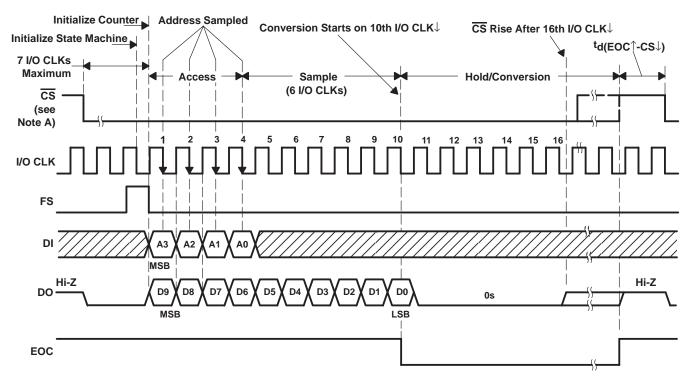
NOTE A: To minimize errors caused by noise at \overline{CS} , the internal circuitry waits for a setup time after \overline{CS} ↓ before responding to control input signals. No attempt should be made to clock in input data until the minimum \overline{CS} setup time has elapsed.

Figure 17. Microprocessor Interface Timing (Normal Sample Mode, INV CLK = Low)



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PARAMETER MEASUREMENT INFORMATION



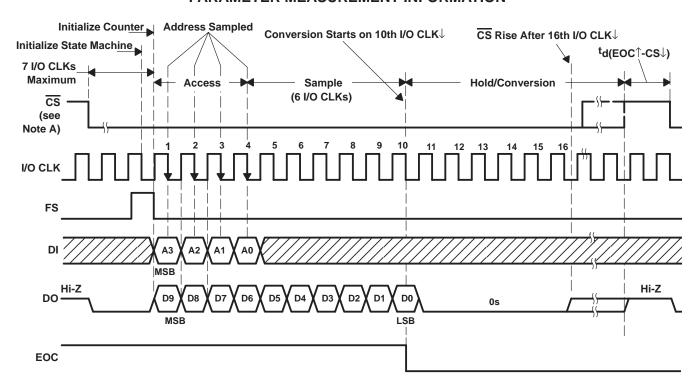
NOTE A: To minimize errors caused by noise at \overline{CS} , the internal circuitry waits for a setup time after \overline{CS} ↓ before responding to control input signals. No attempt should be made to clock in input data until the minimum \overline{CS} setup time elapses.

Figure 18. DSP Interface Timing (16-Clock Transfer, Normal Sample Mode, INV CLK = High)



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PARAMETER MEASUREMENT INFORMATION

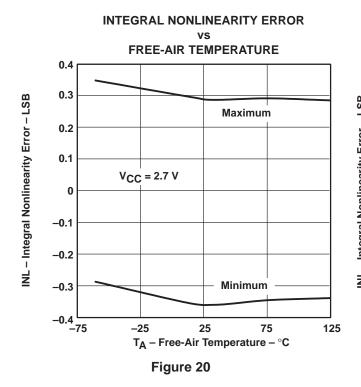


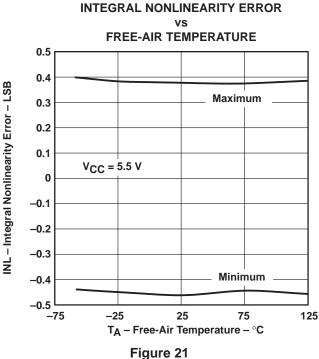
NOTE A: To minimize errors caused by noise at \overline{CS} , the internal circuitry waits for a setup time after \overline{CS} ↓ before responding to control input signals. No attempt should be made to clock in input data until the minimum \overline{CS} setup time elapses.

Figure 19. DSP Interface Timing (16-Clock Transfer, Normal Sample Mode, INV CLK = Low)

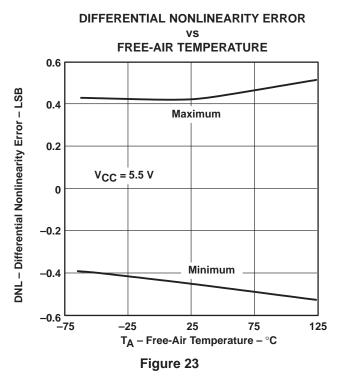


TYPICAL CHARACTERISTICS





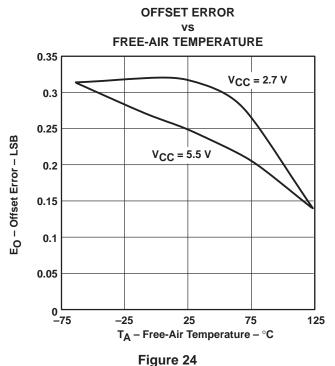
DIFFERENTIAL NONLINEARITY ERROR FREE-AIR TEMPERATURE 0.4 Maximum DNL - Differential Nonlinearity Error - LSB 0.3 0.2 0.1 0 $V_{CC} = 2.7 V$ -0.1-0.2-0.3Minimum -0.4-0.5 -75 125 25 T_A – Free-Air Temperature – $^{\circ}$ C Figure 22

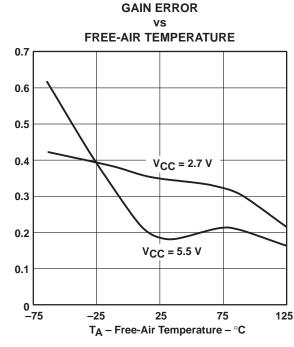


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TYPICAL CHARACTERISTICS

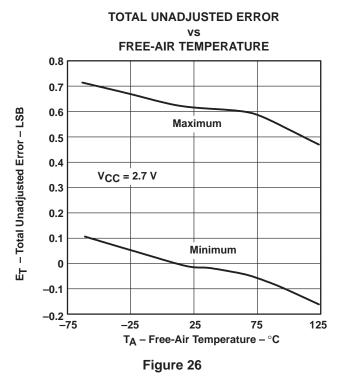
E_G – Gain Error – LSB

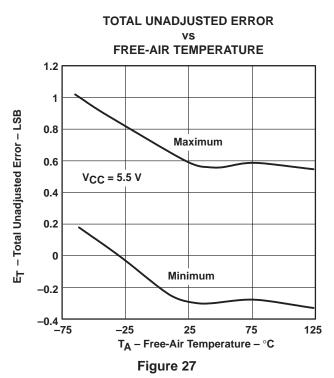




rigure 24







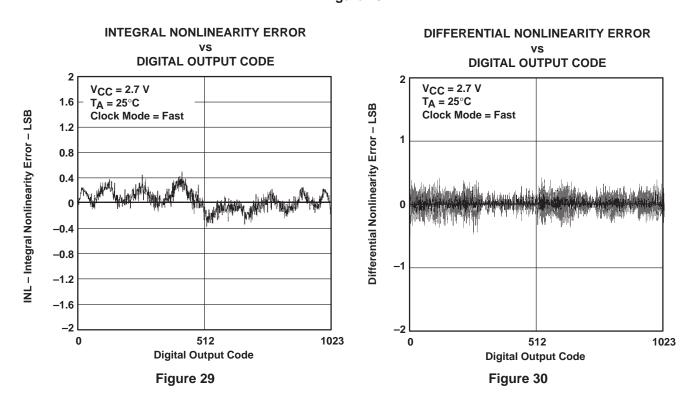
TEXAS

RETRUMENTS COM/TI

TYPICAL CHARACTERISTICS

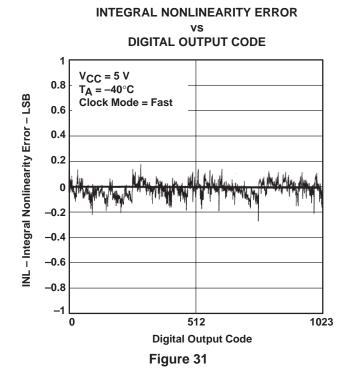
SUPPLY CURRENT FREE-AIR TEMPERATURE 0.56 0.54 0.52 I_{CC}- Supply Current - mA 0.5 0.48 0.46 0.44 V_{CC} = 5.5 V Clock Mode = 0.42 **Fast Conversion** 0.4 - -75 -25 25 125 $T_{\mbox{A}}$ – Free-Air Temperature – $^{\circ}\mbox{C}$

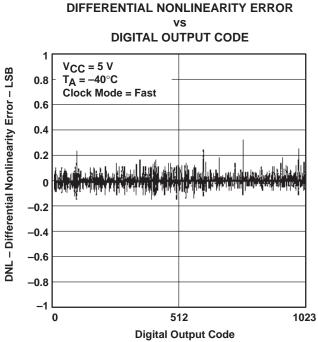
Figure 28



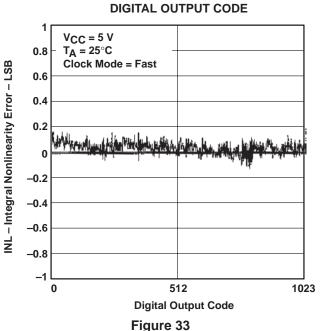
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TYPICAL CHARACTERISTICS



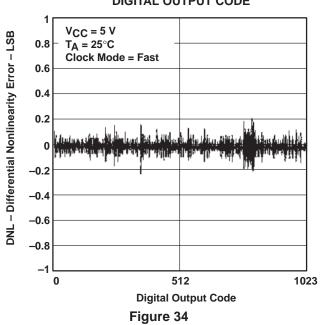


INTEGRAL NONLINEARITY ERROR vs



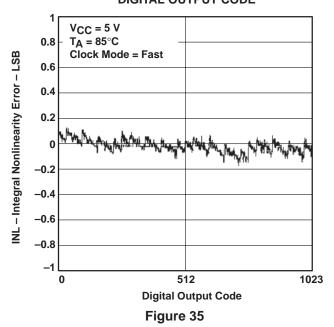
DIFFERENTIAL NONLINEARITY ERROR vs DIGITAL OUTPUT CODE

Figure 32

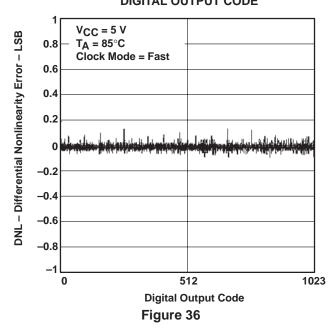


TYPICAL CHARACTERISTICS

INTEGRAL NONLINEARITY ERROR vs DIGITAL OUTPUT CODE

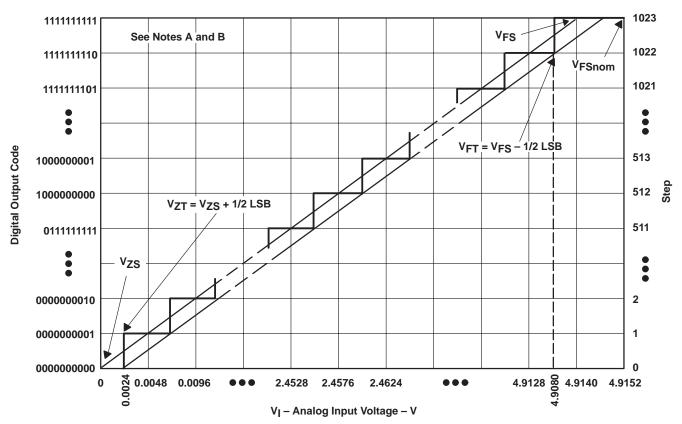


DIFFERENTIAL NONLINEARITY ERROR vs DIGITAL OUTPUT CODE



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APPLICATION INFORMATION

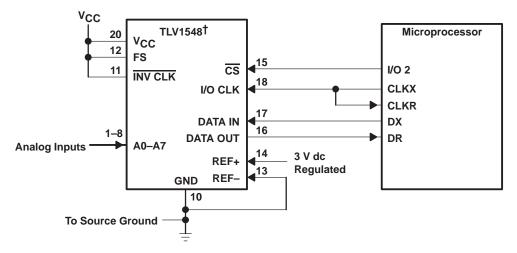


- NOTES: A. This curve is based on the assumption that V_{Tef+} and V_{Tef-} have been adjusted so that the voltage at the transition from digital 0 to 1 (V_{ZT}) is 0.0024 V, and the transition to full scale (V_{FT}) is 4.908 V. 1 LSB = 4.8 mV.
 - B. The full-scale value (VFS) is the step whose nominal midstep value has the highest absolute value. The zero-scale value (VZS) is the step whose nominal midstep value equals zero.

Figure 37. Ideal Conversion Characteristics

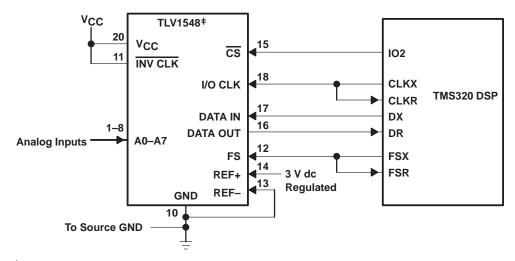


APPLICATION INFORMATION



†DB package is shown for TLV1548

Figure 38. Typical Interface to a Microprocessor



[‡] DB package is shown for TLV1548

Figure 39. Typical Interface to a TMS320 DSP

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APPLICATIONS INFORMATION

simplified analog input analysis

Using the equivalent circuit in Figure 33, the time required to charge the analog input capacitance from 0 to V_S within 1/2 LSB can be derived as follows:

The capacitance charging voltage is given by:

$$V_{C} = V_{S} \left(1 - e^{-t_{C}/R_{t}C_{i}} \right)$$
 where

 $R_t = R_s + r_i$

 t_{c} = Cycle time

The input impedance Z_i is 1 k Ω at 5 V, and is higher (~ 5 k Ω) at 2.7 V. The final voltage to 1/2 LSB is given by:

$$V_C (1/2 LSB) = V_S - (V_S/2048)$$
 (2)

Equating equation 1 to equation 2 and solving for cycle time t_c gives:

$$V_{S} - (V_{S}/2048) = V_{S} (1 - e^{-t_{C}/R_{t}C_{i}})$$
and time to change to 1/2 LSB (minimum sampling time) is:

(3)

io to change to 1/2 200 (minimum camping in 10)

$$t_{ch}$$
 (1/2 LSB) = $R_t \times C_i \times ln(2048)$

where

ln(2048) = 7.625

Therefore, with the values given, the time for the analog input signal to settle is:

$$t_{ch} (1/2 LSB) = (R_S + 1 k\Omega) \times 55 pF \times ln(2048)$$
 (4)

This time must be less than the converter sample time shown in the timing diagrams. Which is 6x I/O CLK.

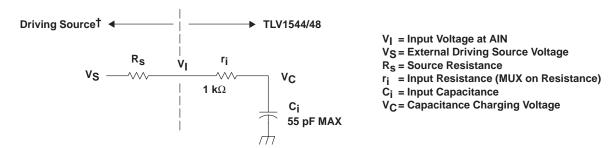
$$t_{ch} (1/2 LSB) \le 6x 1/f_{I/O}$$
 (5)

Therefore the maximum I/O CLK frequency is:

$$\max(f_{I/O}) = 6/t_{ch} (1/2 LSB) = 6/(\ln(2048) \times R_t \times C_i)$$
(6)



APPLICATIONS INFORMATION



† Driving source requirements:

- Noise and distortion for the source must be equivalent to the resolution of the converter.
- R_S must be real at the input frequency.

Figure 40. Equivalent Input Circuit Including the Driving Source

maximum conversion throughput

For a supply voltage at 5 V, if the source impedance is less than 1 k Ω , this equates to a minimum sampling time $t_{ch}(0.5 \text{ LSB})$ of 0.84 μs . Since the sampling time requires six I/O clocks, the fastest I/O clockfrequency is $6/t_{ch} = 7.18$ MHz. The minimal total cycle time is given as:

$$t_{c}$$
 = $t_{address}$ + t_{sample} + t_{conv} + t_{d} (EOC \uparrow - CS \downarrow)
= 0.56 μ s + 0.84 μ s + 10 μ s + 0.1 μ s
= 11.5 μ s

A maximum throughput of 87 KSPS. The throughput can be even higher with a smaller source impedance.

When source impedance is 100Ω , the minimum sampling time is $0.46~\mu s$. The maximum I/O clock frequency possible is almost 13~MHz. Then 10~MHz clock (maximum I/O CLK for TLV1544/1548) can be used. The minimal total cycle time is:

$$t_c$$
 = $t_{address}$ + t_{sample} + t_{conv} + t_{d} (EOC↑ – CS↓)
= $4 \times 1/f$ + 0.46 μs + 10 μs + 0.1 μs
= 0.4 μs + 0.46 μs + 10 μs + 0.1 μs
= 10.96 μs

The maximum throughput is $1/10.96 \, \mu s = 91 \, KSPS$ for this case.

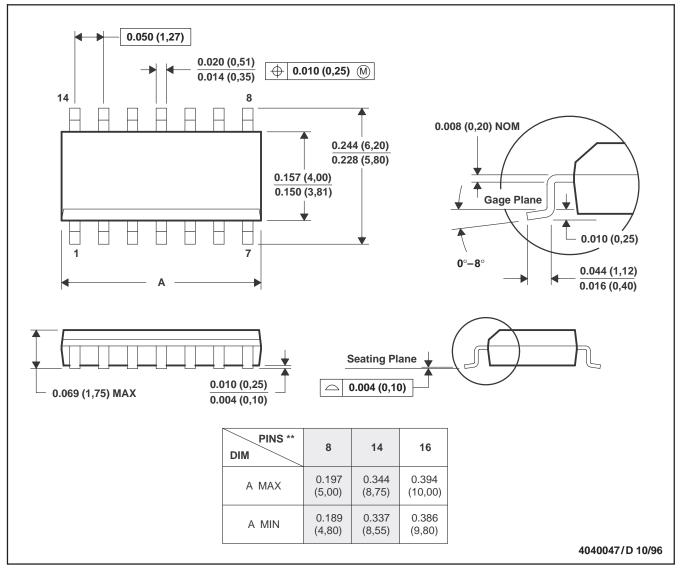
SLAS139C - DECEMBER 1996 - REVISED JANUARY 1999

MECHANICAL DATA

D (R-PDSO-G**)

14 PIN SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).

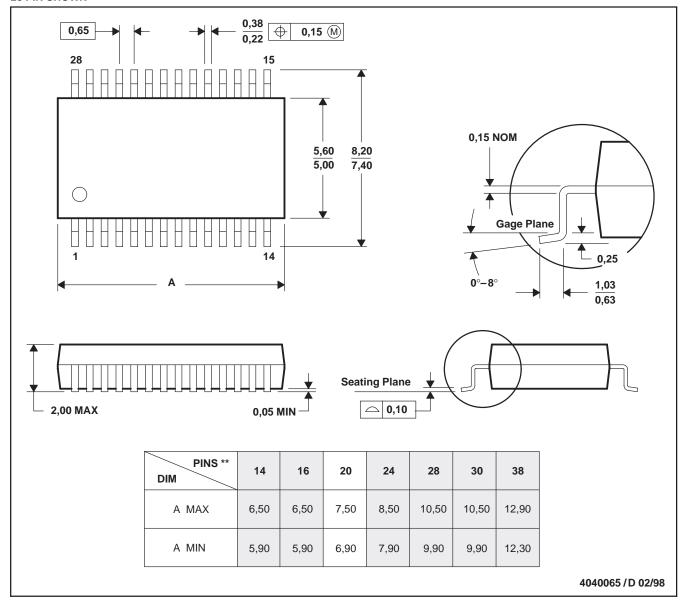
D. Falls within JEDEC MS-012

MECHANICAL DATA

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

28 PIN SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

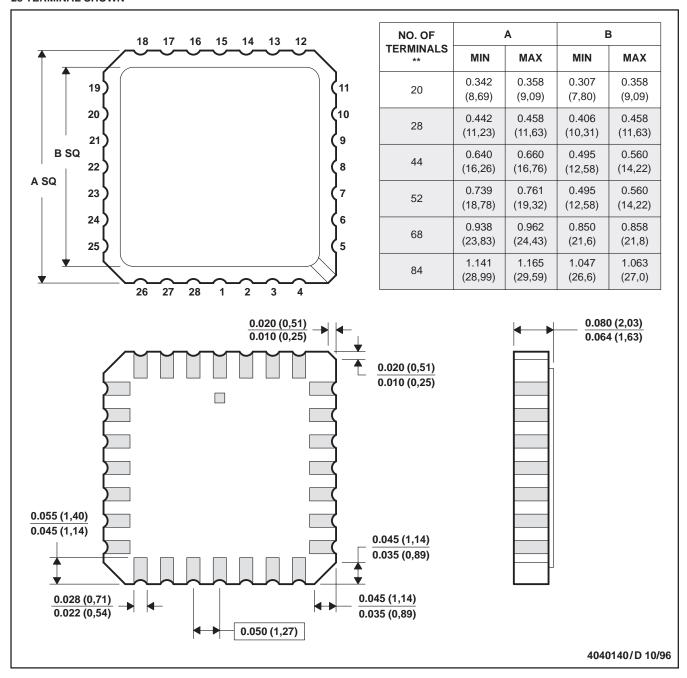
SLAS139C - DECEMBER 1996 - REVISED JANUARY 1999

MECHANICAL DATA

FK (S-CQCC-N**)

28 TERMINAL SHOWN

LEADLESS CERAMIC CHIP CARRIER



- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package can be hermetically sealed with a metal lid.
 - D. The terminals are gold plated.
 - E. Falls within JEDEC MS-004

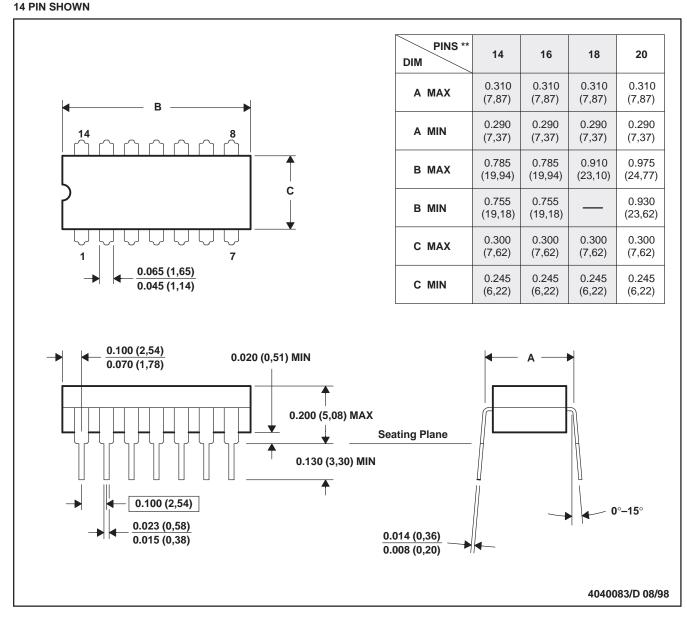


MECHANICAL DATA

J (R-GDIP-T**)

(... 02... .)

CERAMIC DUAL-IN-LINE PACKAGE



- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\hbox{C. \ \ } This \ package \ can \ be \ hermetically \ sealed \ with \ a \ ceramic \ lid \ using \ glass \ frit.$
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18, GDIP1-T20, and GDIP1-T22.



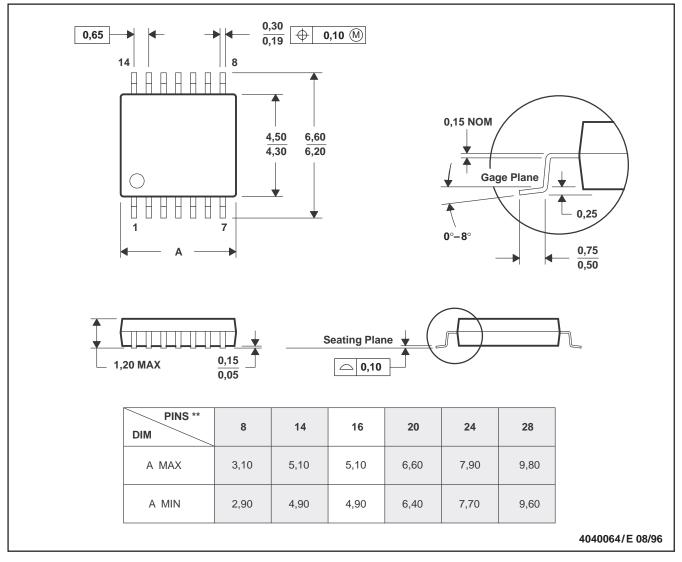
SLAS139C - DECEMBER 1996 - REVISED JANUARY 1999

MECHANICAL DATA

PW (R-PDSO-G**)

14 PIN SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: F. All linear dimensions are in millimeters.

G. This drawing is subject to change without notice.

H. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

I. Falls within JEDEC MO-153



PACKAGE OPTION ADDENDUM

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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
5962-9853801Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
5962-9853801QRA	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type
TLV1544CD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544CDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544CDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544CDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544CPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544CPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544CPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544CPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544ID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544IDG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544IDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544IDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544IPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544IPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544IPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1544IPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1548CDB	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1548CDBG4	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1548CDBLE	OBSOLETE	SSOP	DB	20		TBD	Call TI	Call TI
TLV1548CDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1548CDBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1548IDB	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1548IDBG4	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1548IDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM



PACKAGE OPTION ADDENDUM

16-Oct-2009 www ti com

Orderable Device	Status (1)	Package Type	Package Drawing	Pins P	ackage Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TLV1548IDBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TLV1548MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type
TLV1548MJB	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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OTHER QUALIFIED VERSIONS OF TLV1548, TLV1548M:

• Automotive: TLV1548-Q1

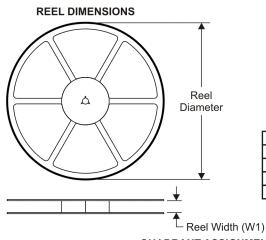
Enhanced Product: TLV1548-EP

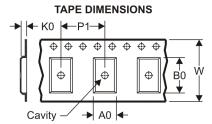
NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV1544CDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TLV1544CPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV1544IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TLV1544IPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV1548CDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
TLV1548IDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV1544CDR	SOIC	D	16	2500	346.0	346.0	33.0
TLV1544CPWR	TSSOP	PW	16	2000	346.0	346.0	29.0
TLV1544IDR	SOIC	D	16	2500	346.0	346.0	33.0
TLV1544IPWR	TSSOP	PW	16	2000	346.0	346.0	29.0
TLV1548CDBR	SSOP	DB	20	2000	346.0	346.0	33.0
TLV1548IDBR	SSOP	DB	20	2000	346.0	346.0	33.0

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